

# Super Low power, CMOS, Rail-to-Rail Operational Amplifier

### Advanced

#### 1. Features

• Single-Supply Operation from +1.4V to +5.5V

• Rail-to-Rail Input/Output

• Gain-Bandwidth Product: 9KHz

Low Input Bias Current: 1pA

• Low Offset Voltage: 1mV

• Quiescent Current: 500nA/Amplifier

• Available in Space-Saving Packages:

• SOP-8 and MSOP-8 Packages

#### 2. General Description

The GT7042 series amplifiers are single supply, low power CMOS dual operational amplifier, these amplifiers offer bandwidth of 9KHz, rail-to-rail inputs and outputs, and single-supply operation from 1.4V to 5.5V. Low quiescent supply current of  $1\mu A$  and very low input bias current of 1pA make the devices an ideal choice for low offset, low power consumption and high impedance applications such as smoke detectors, photodiode amplifiers, and other sensors.

The GT7042 is available in SOP-8 and MSOP-8 packages. The extended temperature range of -40°C to +85°C over all supply voltages offers additional design flexibility.

#### 3. Applications

- Portable Equipment
- Mobile Communications
- Smoke Detector
- Sensor Interface

- Medical Instrumentation
- Battery-Powered Instruments
- Handheld Test Equipment

### 4. Pin Configuration

#### 4.1 GT7042 SOP8 and MSOP8 (Top View)

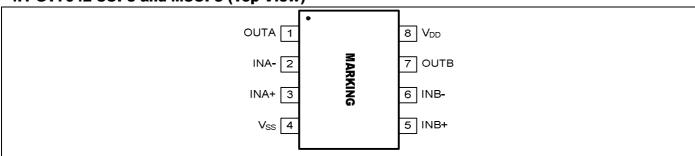


Figure 1. Pin Assignment Diagram (SOP8 and MSOP8 Package)

**Note:** Please see section "**Part Markings**" for detailed Marking Information.

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#### 5. Application Information

#### **5.1 Size**

GT7042series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the GT7042 series packages save space on printed circuit boards and enable the design of smaller electronic products.

#### 5.2 Power Supply Bypassing and Board Layout

GT7042 series operates from a single 1.4V to 5.5V supply or dual  $\pm 0.7V$  to  $\pm 2.75V$  supplies. For best performance, a  $0.1\mu F$  ceramic capacitor should be placed close to the  $V_{DD}$  pin in single supply operation. For dual supply operation, both  $V_{DD}$  and  $V_{SS}$  supplies should be bypassed to ground with separate  $0.1\mu F$  ceramic capacitors.

#### **5.3 Low Supply Current**

The low supply current (1.4µA) of GT7042 series will help to maximize battery life. They are ideal for battery powered systems

#### **5.4 Operating Voltage**

GT7042 series operate under wide input supply voltage (1.4V to 5.5V). In addition, all temperature specifications apply from -40°C to +125°C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime

#### 5.5 Rail-to-Rail Input

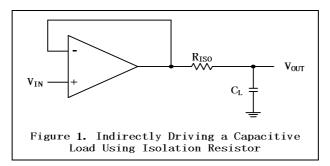
The input common-mode range of GT7042 series extends 100mV beyond the supply rails ( $V_{SS}$ -0.1V to  $V_{DD}$ +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### 5.6 Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of GT7042 series can typically swing to less than 10mV from supply rail in light resistive loads (> $100k\Omega$ ), and 60mV of supply rail in moderate resistive loads ( $10k\Omega$ ).

#### **5.7 Capacitive Load Tolerance**

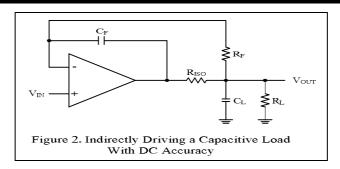
The GT7042 series can directly drive 250pF capacitive load in unity-gain without oscillation. Increasing the gain enhances the amplifier's ability to drive greater capacitive loads. In unity-gain configurations, the capacitive load drive can be improved by inserting an isolation resistor  $R_{\rm ISO}$  in series with the capacitive load, as shown in Figure 1.



The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. However, if there is a resistive load  $R_L$  in parallel with the capacitive load, a voltage divider (proportional to  $R_{ISO}/R_L$ ) is formed, this will result in a gain error.

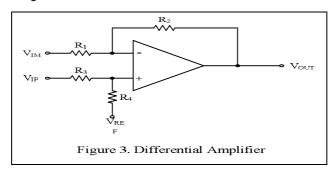
The circuit in Figure 2 is an improvement to the one in Figure 1.  $R_F$  provides the DC accuracy by feed-forward the  $V_{IN}$  to  $R_L$ .  $C_F$  and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of  $C_F$ . This in turn will slow down the pulse response.





#### 5.8 Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 3 shown the differential amplifier using GT7041.



$$V_{out} = (\frac{R_1 + R_2}{R_3 + R_4}) \frac{R_4}{R_1} V_2 - \frac{R_2}{R_1} V_1 + (\frac{R_1 + R_2}{R_3 + R_4}) \frac{R_3}{R_1} \frac{V^+}{2}$$

If the resistor ratios are equal (i.e. R<sub>1</sub>=R<sub>3</sub> and R<sub>2</sub>=R<sub>4</sub>), then

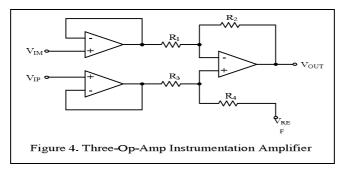
$$V_{out} = \frac{R_2}{R_1} (V_2 - V_1) + \frac{V^+}{2}$$

#### **5.9** Instrumentation Amplifier

The input impedance of the previous differential amplifier is set by the resistors R<sub>1</sub>, R<sub>2</sub>, R<sub>3</sub>, and R<sub>4</sub>. To maintain the high input impedance, one can use a voltage follower in front of each input as shown in the following two instrumentation amplifiers.

#### 5.10 Three-Op-Amp Instrumentation Amplifier

The quad GT7042 can be used to build a three-op-amp instrumentation amplifier as shown in Figure 4.

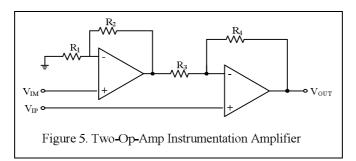


The amplifier in Figure 4 is a high input impedance differential amplifier with gain of  $R_2/R_1$ . The two differential voltage

followers assure the high input impedance of the amplifier.

#### 5.11 Two-Op-Amp Instrumentation Amplifier

GT7042 can also be used to make a high input impedance two-op-amp instrumentation amplifier as shown in Figure 5.

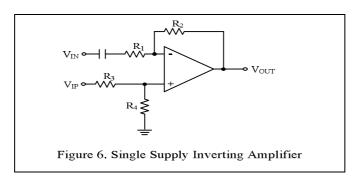


$$V_o = (1 + \frac{R_4}{R_3})(V_2 - V_1)$$

Where  $R_1=R_3$  and  $R_2=R_4$ . If all resistors are equal, then  $V_0=2(V_2-V_1)$ 

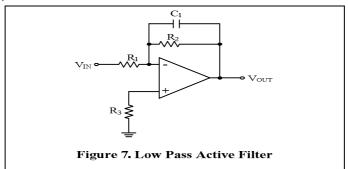
#### **5.12 Single-Supply Inverting Amplifier**

The inverting amplifier is shown in Figure 6. The capacitor C<sub>1</sub> is used to block the DC signal going into the AC signal source V<sub>IN</sub>. The value of  $R_1$  and  $C_1$  set the cut-off frequency to  $f_C=1/(2\pi R_1C_1)$ . The DC gain is defined by  $V_{OUT}=-(R_2/R_1)V_{IN}$ 



#### **5.13 Low Pass Active Filter**

The low pass active filter is shown in Figure 7. The DC gain is defined by  $-R_2/R_1$ . The filter has a -20dB/decade roll-off after its corner frequency  $f_C=1/(2\pi R_3 C_1)$ .



#### 5.14 Sallen-Key 2<sup>nd</sup> Order Active Low-Pass Filter

GT7042 can be used to form a 2<sup>nd</sup> order Sallen-Key active low-pass filter as shown in Figure 8. The transfer function from V<sub>IN</sub> to

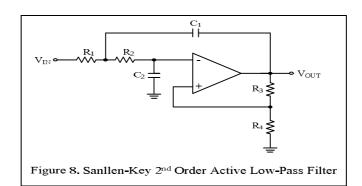


$$\frac{V_{OUT}}{V_{in}}(S) = \frac{\frac{1}{C_1C_2R_1R_2}A_{LP}}{S^2 + S(\frac{1}{C_1R_1} + \frac{1}{C_1R_2} + \frac{1}{C_2R_2} - \frac{A_{LP}}{C_2R_2}) + \frac{1}{C_1C_2R_1R_2}}$$

Where the DC gain is defined by A<sub>LP</sub>=1+R<sub>3</sub>/R<sub>4</sub>, and the corner frequency is given by  $\omega C = \sqrt{\frac{1}{C_1 C_2 R_1 R_2}}$ 

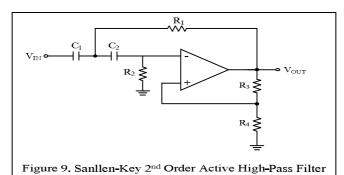
The pole quality factor is given by  $\frac{\omega C}{Q} = \frac{1}{C_1 R_1} + \frac{1}{C_1 R_2} + \frac{1}{C_2 R_2} - \frac{A_{LP}}{C_2 R_2}$ 

Let R1=R2=R and C1=C2=C, the corner frequency and the pole quality factor can be simplified as below  $\omega_C = \frac{1}{CR}$  And Q=2-R<sub>3</sub>/R<sub>4</sub>



### 5.15 Sallen-Key 2<sup>nd</sup> Order high-Pass Active Filter

The 2<sup>nd</sup> order Sallen-key high-pass filter can be built by simply interchanging those frequency selective components R<sub>1</sub>, R<sub>2</sub>, C<sub>1</sub>, and C2 as shown in Figure 9.



$$\frac{V_{OUT}}{V_{IN}}(S) = \frac{S^2 A_{HP}}{S^2 + S(\frac{1}{C_1 R_1} + \frac{1}{C_2 R_2} + \frac{1 - A_{HP}}{C_1 R_1}) + \frac{1}{C_1 C_2 R_1 R_2}}$$

Where A<sub>HP</sub>=1+R<sub>3</sub>/R<sub>4</sub>



### 6. Electrical Characteristics

#### **6.1 Absolute Maximum Ratings**

Condition	Min	Max			
Power Supply Voltage (V <sub>DD</sub> to Vss)	-0.5V +7V				
Analog Input Voltage (IN+ or IN-)	Vss-0.5V V <sub>DD</sub> +0.5V				
PDB Input Voltage	Vss-0.5V +7V				
Operating Temperature Range	-40°C	+85°C			
Junction Temperature	+150°C				
Storage Temperature Range	-65°C	+150°C			
Lead Temperature (soldering, 10sec)	+300°C				
Package Thermal Resistance (T <sub>A</sub> =+25°C)					
MSOP-8, θ <sub>JA</sub>	210°C				
SOP8, θ <sub>JA</sub>	130°C				

**Note:** Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



#### **6.2 Electrical Characteristics**

 $(V_{DD}$  = +5V, Vss = 0V,  $V_{CM}$  =  $V_{DD}/2$ ,  $V_{OUT}$  =  $V_{DD}/2$ ,  $R_L$ =100K tied to  $V_{DD}/2$ , SHDNB =  $V_{DD}$ ,  $T_A$  = -40°C to 85°C, unless otherwise noted. Typical values are at T<sub>A</sub> =+25°C.) (Notes 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIS
Supply-Voltage Range	$V_{DD}$	Guaranteed by the PSRR test	1.4		5.5	V
Quiescent Supply Current		VDD = 5V		1.0	2.0	μΑ
(per Amplifier)	$I_Q$	Shutdown Mode (PDB = $V_{SS}$ )		0.1		μΑ
Input Offset Voltage	Vos			1	±5	mV
Input Offset Voltage	ΔVos/ΔT			0.5		μV/°C
Tempco						
Input Bias Current	$I_{B}$	(Note 2)		1		pA
Input Offset Current	Ios	(Note 2)		1		pA
Input Common-Mode	$V_{CM}$		-0.1		V <sub>DD</sub> +0.1	V
Voltage Range						
Common-Mode Rejection	CMRR	$V_{DD}$ =5.5 Vss-0.1 V $\leq V_{CM} \leq V_{DD}$ +0.1 V	60	75		dB
Ratio		$V_{SS} \leq V_{CM} \leq 5V$	65	80		
Power-Supply Rejection	PSRR	$V_{DD} = +1.8 \text{ V to } +5.5 \text{ V}$	65	80		dB
Ratio						
Open-Loop Voltage Gain	$A_{V}$	$V_{DD}$ =5V, $R_L$ =50k $\Omega$ ,		90		dB
		0.1V≤V <sub>0</sub> ≤4.9V				
		$V_{DD}$ =1.4V, $R_L$ =50k $\Omega$ ,		80		dB
		0.1V≤V <sub>0</sub> ≤4.9V				
Output Voltage Swing	$V_{OUT}$	$ V_{\text{IN+}}-V_{\text{IN-}}  \ge 10 \text{mV}$ $V_{\text{DD}}-V_{\text{OH}}$		6		mV
		$R_L = 100 k\Omega$ to $V_{DD}/2$ $V_{OL}$ -Vss		6		
		$ V_{\text{IN+}}-V_{\text{IN-}}  \ge 10 \text{mV}$ $V_{\text{DD}}-V_{\text{OH}}$		40		
		$R_L = 50 k\Omega$ to $V_{DD}/2$ $V_{OL}-V_{SS}$		40		
Output Short-Circuit	$I_{SC}$	Sinking or Sourcing		±3		mA
Current						
Gain Bandwidth Product	GBW	$A_{V} = +1V/V$		9		KHz
Slew Rate	SR	$A_V = +1V/V$		4.5		V/ms
Settling Time	$t_{\rm s}$	To 0.1%, $V_{OUT} = 2V$ step		650		μs
		$A_{V} = +1V/V$				
Input Voltage Noise	en	$V_{DD}$ =5V, f = 1kHz		150		nV/√Hz
Density		$V_{DD}=1.4V$ , $f=1kHz$		150		

**Note 1:** All devices are 100% production tested at  $T_A = 25$ °C; all specifications over the automotive temperature range is guaranteed by design, not production tested.

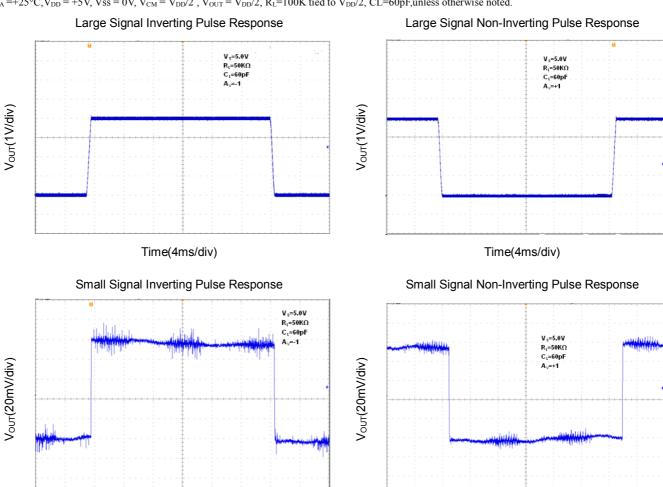
Parameter is guaranteed by design. Note 2:





#### **6.3 Typical performance characteristics**

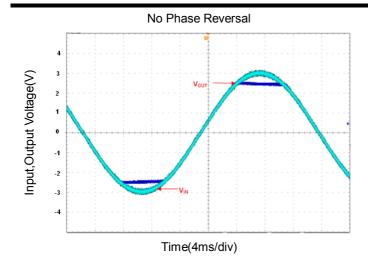
 $T_A = +25 ^{\circ}C, V_{DD} = +5 V, \ V_{SS} = 0 V, \ V_{CM} = V_{DD}/2 \ , \ V_{OUT} = V_{DD}/2, \ R_L = 100 K \ tied \ to \ V_{DD}/2, \ CL = 60 pF, unless \ otherwise \ noted.$ 

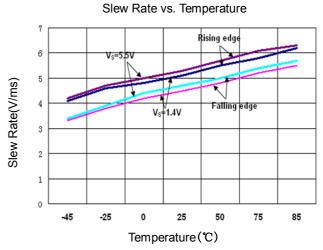


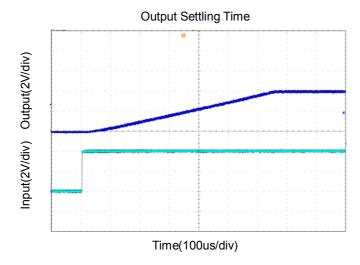
Time(4ms/div)

Time(4ms/div)



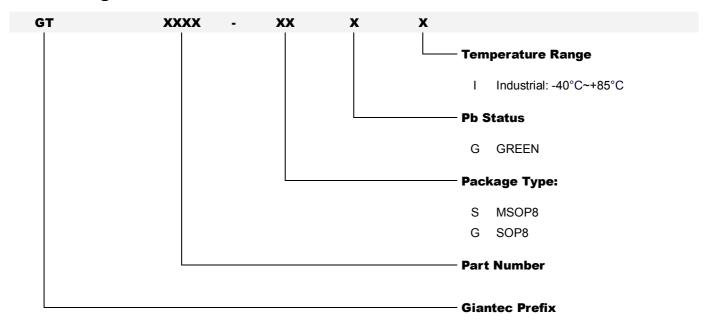








### 7. Ordering Information



GT Giantec

Order Number	Package Description	Package Option
GT7042-SGI-TR	MSOP8	Tape and Reel 4000
GT7042-GGI-TR	SOP8	Tape and Reel 4000

### 8. Part Markings

### 8.1 GT7042 (Top View)

<b>GT</b> 7	0 4	<u>Y</u> <u>W</u>	
GT7042	GT7042-SGI		
•	Pin 1 Indicator		
Y	Seal Year	W	Seal Week
2010 (1st half year)	A	Week 01	Α
2010 (2nd half year)	В	Week 02	В
2011 (1st half year)	С		
2011 (2nd half year)	D	Week 26	Z
2012 (1st half year)	E	Week 27	Α
2012 (2nd half year)	F	Week 28	В
2022 (2nd half year)	Z	Week 52	Z



# 8.2 GT7042-GGI (Top View)

<u>G</u>	<u>T</u>					<u> </u>	G	
				Lot Number				
•		<u>Y</u>	<u>Y</u>	<u>w</u>	w	<u>s</u>	<u>v</u>	

#### GT7042GGI

**WW** 

S

**Lot Number** States the last 9 characters of the wafer lot information

● Pin 1 Indicator

YY Seal Year

00 = 2000

01 = 2001

99 = 2099 Seal Week 01 = Week 1

02 = Week 2

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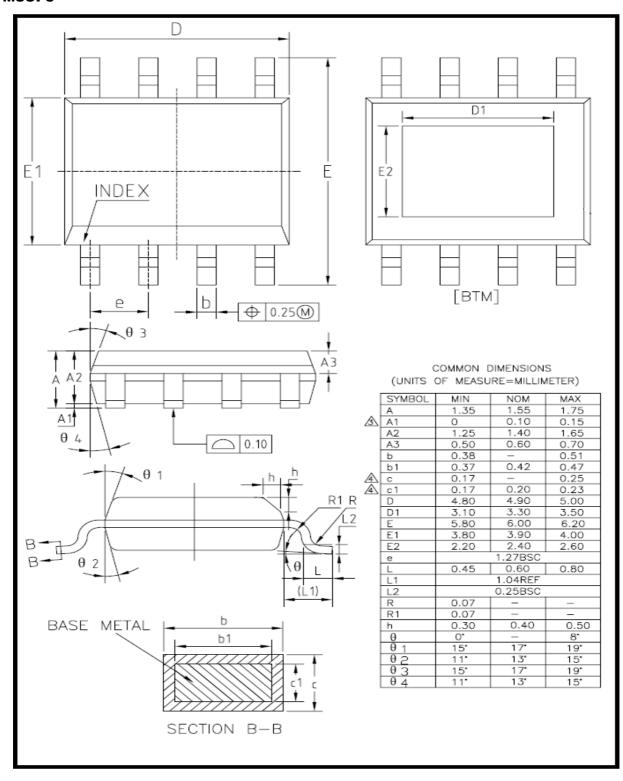
51 = Week 51 52 = Week 52 Subcon Code J = ASESH

L = ASEKS
Die Version



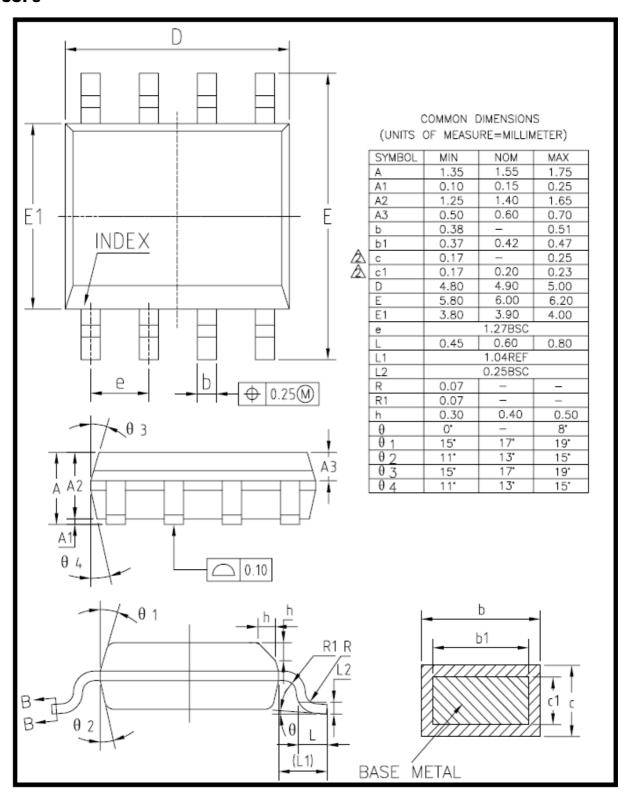
### 9. Package Information

#### 9.1 MSOP8





#### 9.2 SOP8





### 10. Revision History

Revision	Date	Descriptions
A0	July,2013	Version 0